



## T08xxH Series 8A TRIACs

Rev.6.0

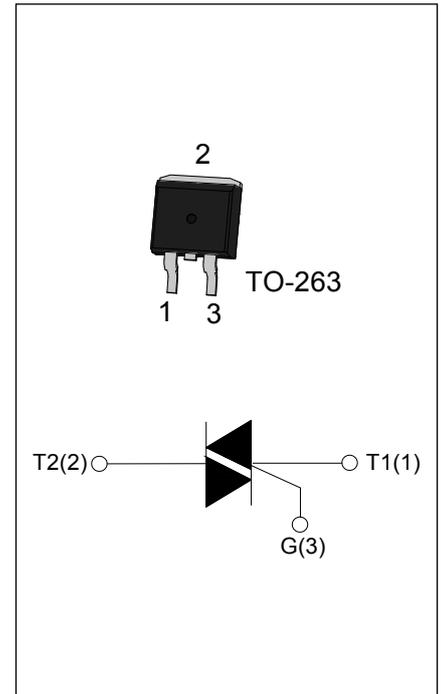
### DESCRIPTION:

T08xxH series triacs of high junction temperature with high dv/dt rate with strong resistance to electromagnetic interference provide high ability to withstand the shock loading of large current. They are especially recommended for use on inductive load and high environment temperature condition.

Package TO-263 is RoHS compliant. (2011/65/EU)

### MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	8	A
$V_{DRM}/V_{RRM}$	600/800	V
$T_{jmax}$	150	°C



### ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	°C
Operating junction temperature range	$T_j$	-40-150	°C
Repetitive peak off-state voltage( $T_j=25^\circ\text{C}$ )	$V_{DRM}$	600/800	V
Repetitive peak reverse voltage( $T_j=25^\circ\text{C}$ )	$V_{RRM}$	600/800	V
RMS on-state current	$I_{T(RMS)}$	8	A
TO-263 ( $T_C=130^\circ\text{C}$ )			
Non repetitive surge peak on-state current (full cycle, F=50Hz)	$I_{TSM}$	80	A
$I^2t$ value for fusing ( $t_p=10\text{ms}$ )	$I^2t$	36	$\text{A}^2\text{s}$
Critical rate of rise of on-state current ( $I_G=2 \times I_{GT}$ )	$di/dt$	50	$\text{A}/\mu\text{s}$
Peak gate current	$I_{GM}$	4	A
Average gate power dissipation	$P_{G(AV)}$	1	W
Peak gate power	$P_{GM}$	5	W

ELECTRICAL CHARACTERISTICS ( $T_j=25^{\circ}\text{C}$  unless otherwise specified)

Symbol	Test Condition	Quadrant		Value				Unit
				T0810H	T0820H	T0835H	T0850H	
$I_{GT}$	$V_D=12\text{V } R_L=33\Omega$	I - II -III	MAX	10	20	35	50	mA
$V_{GT}$		I - II -III	MAX	1.3				V
$V_{GD}$	$V_D=V_{DRM} T_j=150^{\circ}\text{C}$ $R_L=3.3\text{K}\Omega$	I - II -III	MIN	0.2				V
$I_L$	$I_G=1.2I_{GT}$	I -III	MAX	20	40	50	70	mA
		II		35	55	70	80	
$I_H$	$I_T=100\text{mA}$		MAX	20	30	45	60	mA
dV/dt	$V_D=2/3V_{DRM} R_{GK}=1\text{K}\Omega T_j=150^{\circ}\text{C}$		MIN	200	500	1000	1500	V/ $\mu\text{s}$

## STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX)	Unit
$V_{TM}$	$I_{TM}=11\text{A } t_p=380\mu\text{s}$	$T_j=25^{\circ}\text{C}$	1.4	V
$I_{DRM}$	$V_D=V_{DRM} V_R=V_{RRM}$	$T_j=25^{\circ}\text{C}$	5	$\mu\text{A}$
$I_{RRM}$		$T_j=150^{\circ}\text{C}$	1.5	mA

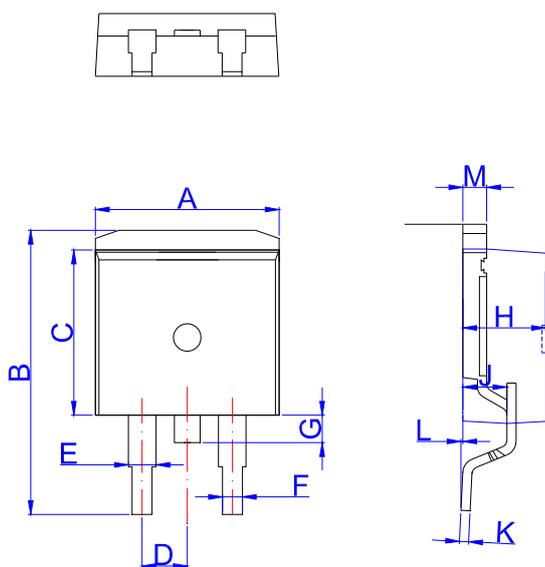
## THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	junction to case(AC)	TO-263	1.3	$^{\circ}\text{C}/\text{W}$
$R_{th(j-a)}$	junction to ambient		45	

ORDERING INFORMATION

<b>T</b>	<b>08</b>	<b>20</b>	<b>H</b>	<b>-6</b>	<b>E</b>
Triacs	$I_{T(RMS)}:8A$				E:TO-263 ETR:TO-263(Tape&Reel)
	10: $I_{GT1-3} \leq 10mA$ 20: $I_{GT1-3} \leq 20mA$ 35: $I_{GT1-3} \leq 35mA$ 50: $I_{GT1-3} \leq 50mA$			6: $V_{DRM} / V_{RRM} \geq 600V$ 8: $V_{DRM} / V_{RRM} \geq 800V$	
			High junction temperature		

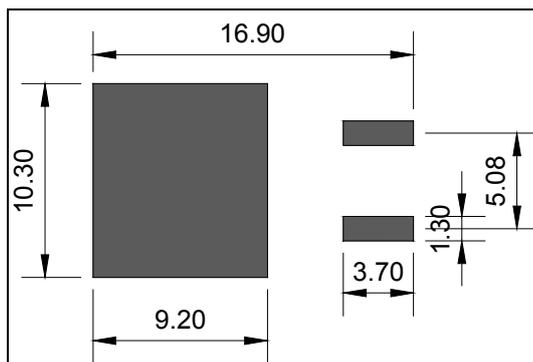
PACKAGE MECHANICAL DATA



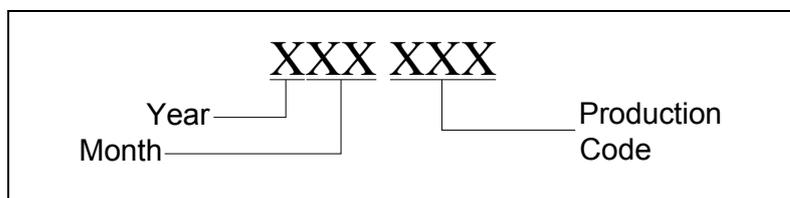
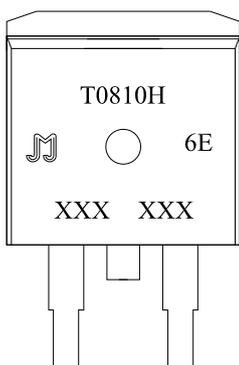
TO-263

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.90		10.20	0.390		0.402
B	14.70		15.80	0.579		0.622
C	9.4		9.6	0.37		0.378
D		2.54			0.100	
E	1.20		1.40	0.047		0.055
F	0.75		0.85	0.029		0.033
G			1.75			0.069
H	4.40		4.70	0.173		0.185
J	2.30		2.70	0.091		0.106
K	0.38		0.55	0.015		0.022
L	0	0.10	0.25	0	0.004	0.010
M	1.25		1.35	0.049		0.053

FOOTPRINT-TO-263 (dimensions in mm)



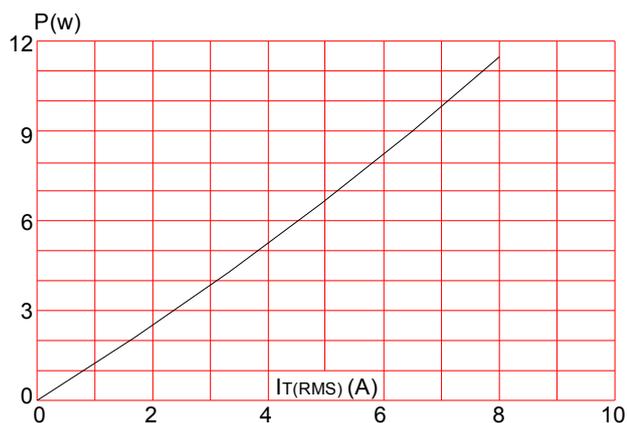
MARKING



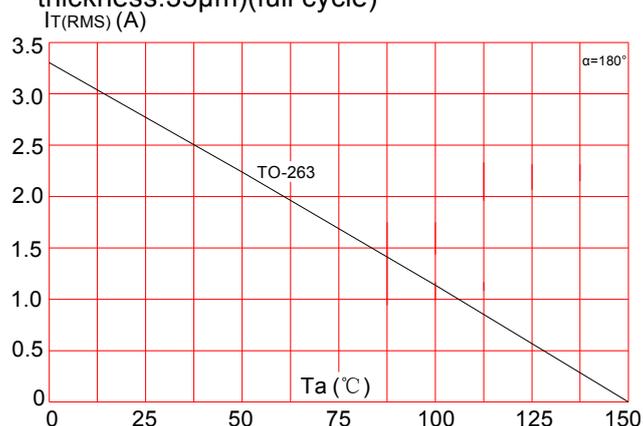
PACKAGE INFORMATION

PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-263	TUBE	50	1,000	6,000
PACKAGE	OUTLINE	REEL (PCS)	PER CARTON (PCS)	TAPE & REEL
TO-263	TAPING	800	4,000	13 inch

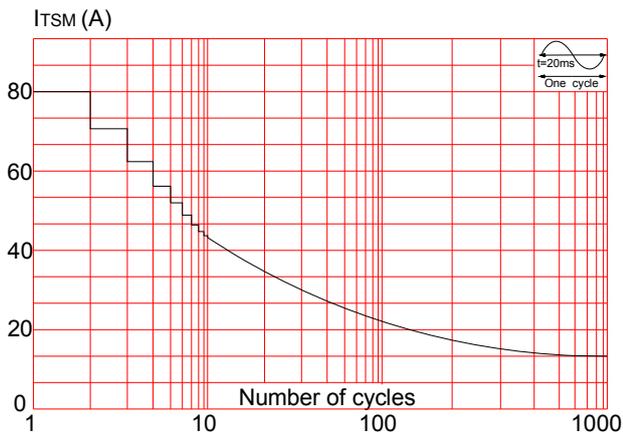
**FIG.1:** Maximum power dissipation versus RMS on-state current



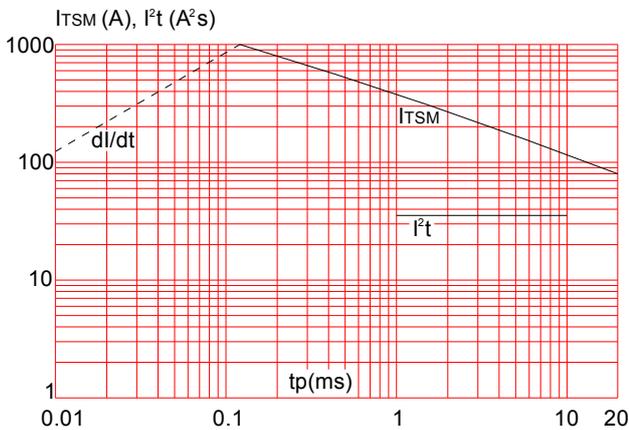
**FIG.2:** RMS on-state current versus ambient temperature (printed circuit board FR4,copper thickness:35 $\mu$ m)(full cycle)



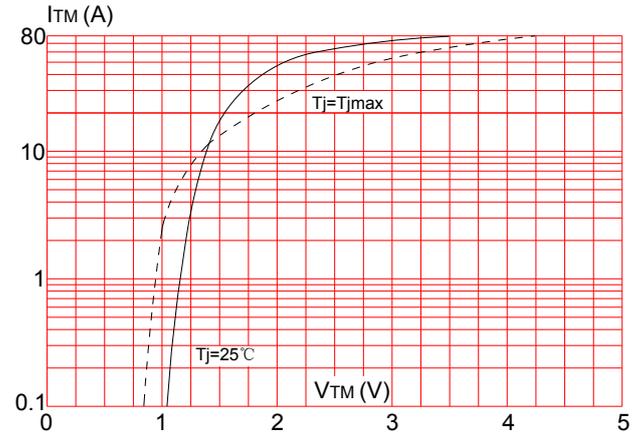
**FIG.3:** Surge peak on-state current versus number of cycles



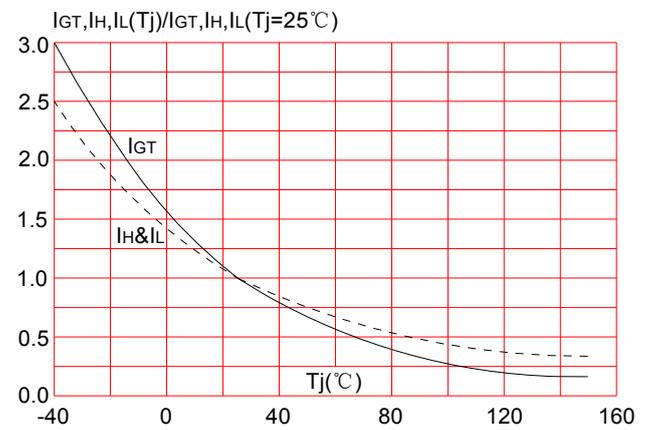
**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 20ms$ , and corresponding value of  $I^2t$  ( $di/dt < 50A/\mu s$ )



**FIG.4:** On-state characteristics (maximum values)

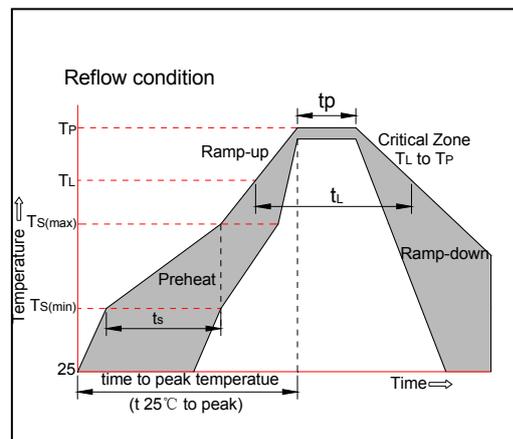


**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature



**SOLDERING PARAMETERS**

Reflow Condition		Pb-Free assembly (see figure at right)
Pre Heat	-Temperature Min ( $T_{s(min)}$ )	+150°C
	-Temperature Max( $T_{s(max)}$ )	+200°C
	-Time (Min to Max) ( $t_s$ )	60-180 secs.
Average ramp up rate (Liquidus Temp ( $T_L$ )to peak)		3°C/sec. Max
$T_{s(max)}$ to $T_L$ - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature( $T_L$ )(Liquidus)	+217°C
	-Temperature( $t_L$ )	60-150 secs.
Peak Temp ( $T_p$ )		+260(+0/-5)°C
Time within 5°C of actual Peak Temp ( $t_p$ )		20-40secs.
Ramp-down Rate		6°C/sec. Max
Time 25°C to Peak Temp ( $T_p$ )		8 min. Max
Do not exceed		+260°C



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